



**THE DATASHEET OF**  
**2N3772G**



# 2N3771, 2N3772

2N3771 is a Preferred Device

## High Power NPN Silicon Power Transistors

These devices are designed for linear amplifiers, series pass regulators, and inductive switching applications.

### Features

- Forward Biased Second Breakdown Current Capability  
 $I_{S/b} = 3.75 \text{ Adc @ } V_{CE} = 40 \text{ Vdc} - 2N3771$   
 $= 2.5 \text{ Adc @ } V_{CE} = 60 \text{ Vdc} - 2N3772$
- Pb-Free Packages are Available\*

### MAXIMUM RATINGS (Note 1)

Rating	Symbol	2N3771	2N3772	Unit
Collector-Emitter Voltage	$V_{CEO}$	40	60	Vdc
Collector-Emitter Voltage	$V_{CEX}$	50	80	Vdc
Collector-Base Voltage	$V_{CB}$	50	100	Vdc
Emitter-Base Voltage	$V_{EB}$	5.0	7.0	Vdc
Collector Current – Continuous Peak	$I_C$	30 30	20 30	Adc
Base Current – Continuous Peak	$I_B$	7.5 15	5.0 15	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	150 0.855		W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200		$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$\theta_{JC}$	1.17	$^\circ\text{C/W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates JEDEC registered data.

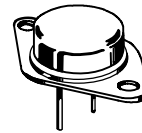


**ON Semiconductor®**

<http://onsemi.com>

**20 and 30 AMPERE  
POWER TRANSISTORS  
NPN SILICON  
40 and 60 VOLTS, 150 WATTS**

### MARKING DIAGRAM



**TO-204AA (TO-3)  
CASE 1-07  
STYLE 1**



2N377x = Device Code  
 x = 1 or 2  
 G = Pb-Free Package  
 A = Assembly Location  
 YY = Year  
 WW = Work Week  
 MEX = Country of Origin

### ORDERING INFORMATION

Device	Package	Shipping
2N3771	TO-204	100 Units / Tray
2N3771G	TO-204 (Pb-Free)	100 Units / Tray
2N3772	TO-204	100 Units / Tray
2N3772G	TO-204 (Pb-Free)	100 Units / Tray

**Preferred** devices are recommended choices for future use and best overall value.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## 2N3771, 2N3772

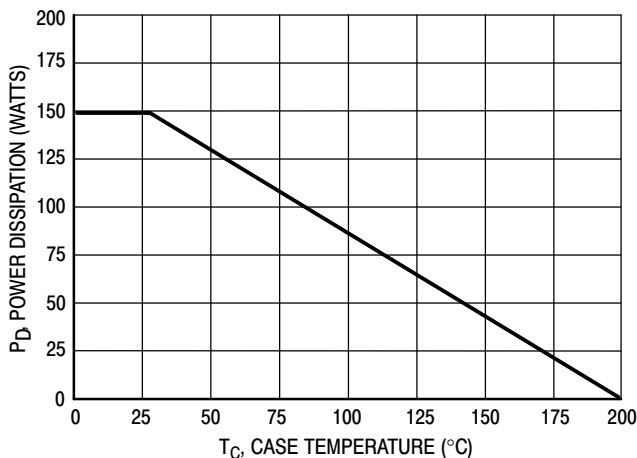
### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector–Emitter Sustaining Voltage (Note 2 and 3) (I <sub>C</sub> = 0.2 Adc, I <sub>B</sub> = 0)	2N3771 2N3772	V <sub>CEO(sus)</sub>	40 60	– –	Vdc
Collector–Emitter Sustaining Voltage (I <sub>C</sub> = 0.2 Adc, V <sub>EB(off)</sub> = 1.5 Vdc, R <sub>BE</sub> = 100 Ω)	2N3771 2N3772	V <sub>CEX(sus)</sub>	50 80	– –	Vdc
Collector–Emitter Sustaining Voltage (I <sub>C</sub> = 0.2 Adc, R <sub>BE</sub> = 100 Ω)	2N3771 2N3772	V <sub>CER(sus)</sub>	45 70	– –	Vdc
Collector Cutoff Current (Note 2) (V <sub>CE</sub> = 30 Vdc, I <sub>B</sub> = 0) (V <sub>CE</sub> = 50 Vdc, I <sub>B</sub> = 0) (V <sub>CE</sub> = 25 Vdc, I <sub>B</sub> = 0)	2N3771 2N3772	I <sub>CEO</sub>	– –	10 10	mAdc
Collector Cutoff Current (Note 2) (V <sub>CE</sub> = 50 Vdc, V <sub>EB(off)</sub> = 1.5 Vdc) (V <sub>CE</sub> = 100 Vdc, V <sub>EB(off)</sub> = 1.5 Vdc) (V <sub>CE</sub> = 45 Vdc, V <sub>EB(off)</sub> = 1.5 Vdc) (V <sub>CE</sub> = 30 Vdc, V <sub>EB(off)</sub> = 1.5 Vdc, T <sub>C</sub> = 150°C)  (V <sub>CE</sub> = 45 Vdc, V <sub>EB(off)</sub> = 1.5 Vdc, T <sub>C</sub> = 150°C)	2N3771 2N3772 2N6257 2N3771 2N3772	I <sub>CEV</sub>	– – – – –	2.0 5.0 4.0 10 10	mAdc
Collector Cutoff Current (Note 2) (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 100 Vdc, I <sub>E</sub> = 0)	2N3771 2N3772	I <sub>CB0</sub>	– –	2.0 5.0	mAdc
Emitter Cutoff Current (Note 2) (V <sub>BE</sub> = 5.0 Vdc, I <sub>C</sub> = 0) (V <sub>BE</sub> = 7.0 Vdc, I <sub>C</sub> = 0)	2N3771 2N3772	I <sub>EBO</sub>	– –	5.0 5.0	mAdc
<b>ON CHARACTERISTICS (Note 2)</b>					
DC Current Gain (Note 3) (I <sub>C</sub> = 15 Adc, V <sub>CE</sub> = 4.0 Vdc) (I <sub>C</sub> = 10 Adc, V <sub>CE</sub> = 4.0 Vdc) (I <sub>C</sub> = 8.0 Adc, V <sub>CE</sub> = 4.0 Vdc) (I <sub>C</sub> = 30 Adc, V <sub>CE</sub> = 4.0 Vdc) (I <sub>C</sub> = 20 Adc, V <sub>CE</sub> = 4.0 Vdc)	2N3771 2N3772 2N3771 2N3772	h <sub>FE</sub>	15 15 5.0 5.0	60 60 – –	–
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 15 Adc, I <sub>B</sub> = 1.5 Adc) (I <sub>C</sub> = 10 Adc, I <sub>B</sub> = 1.0 Adc) (I <sub>C</sub> = 30 Adc, I <sub>B</sub> = 6.0 Adc) (I <sub>C</sub> = 20 Adc, I <sub>B</sub> = 4.0 Adc)	2N3771 2N3772 2N3771 2N3772	V <sub>CE(sat)</sub>	– – – –	2.0 1.4 4.0 4.0	Vdc
Base–Emitter On Voltage (I <sub>C</sub> = 15 Adc, V <sub>CE</sub> = 4.0 Vdc) (I <sub>C</sub> = 10 Adc, V <sub>CE</sub> = 4.0 Vdc) (I <sub>C</sub> = 8.0 Adc, V <sub>CE</sub> = 4.0 Vdc)	2N3771 2N3772	V <sub>BE(on)</sub>	– –	2.7 2.2	Vdc
<b>*DYNAMIC CHARACTERISTICS (Note 2)</b>					
Current–Gain — Bandwidth Product (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 4.0 Vdc, f <sub>test</sub> = 50 kHz)		f <sub>T</sub>	0.2	–	MHz
Small–Signal Current Gain (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 4.0 Vdc, f = 1.0 kHz)		h <sub>fe</sub>	40	–	–
<b>SECOND BREAKDOWN</b>					
Second Breakdown Energy with Base Forward Biased, t = 1.0 s (non–repetitive) (V <sub>CE</sub> = 40 Vdc) (V <sub>CE</sub> = 60 Vdc)	2N3771 2N3772	I <sub>S/b</sub>	3.75 2.5	– –	Adc

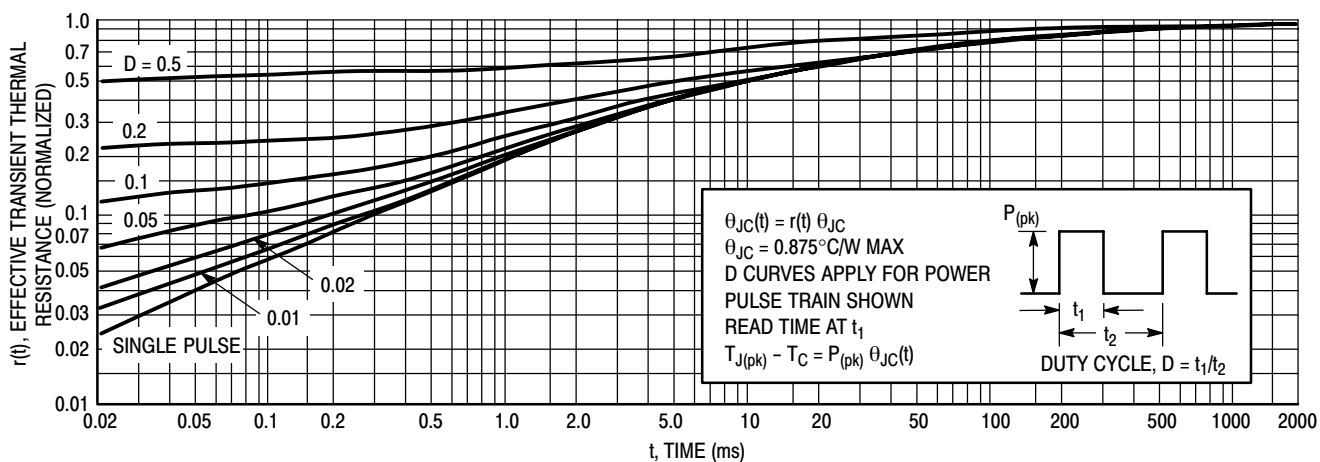
2. Indicates JEDEC registered data.

3. Pulse Test: 300 μs, Rep. Rate 60 cps.

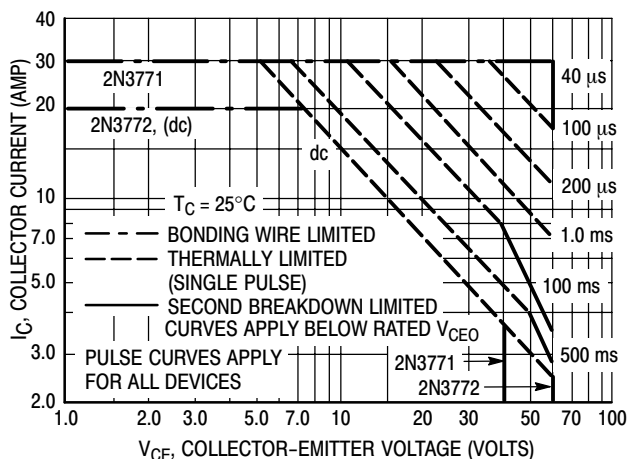
## 2N3771, 2N3772



**Figure 1. Power Derating**



**Figure 2. Thermal Response — 2N3771, 2N3772**



**Figure 3. Active-Region Safe Operating Area — 2N3771, 2N3772**

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation: i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

Figure 3 is based on JEDEC registered Data. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} < 200^{\circ}\text{C}$ .  $T_{J(pk)}$  may be calculated from the data of Figure 2. Using data of Figure 2 and the pulse power limits of Figure 3,  $T_{J(pk)}$  will be found to be less than  $T_{J(max)}$  for pulse widths of 1 ms and less. When using ON Semiconductor transistors, it is permissible to increase the pulse power limits until limited by  $T_{J(max)}$ .

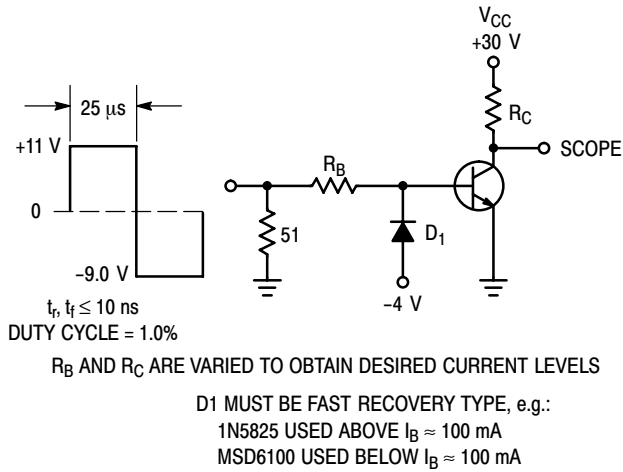


Figure 4. Switching Time Test Circuit

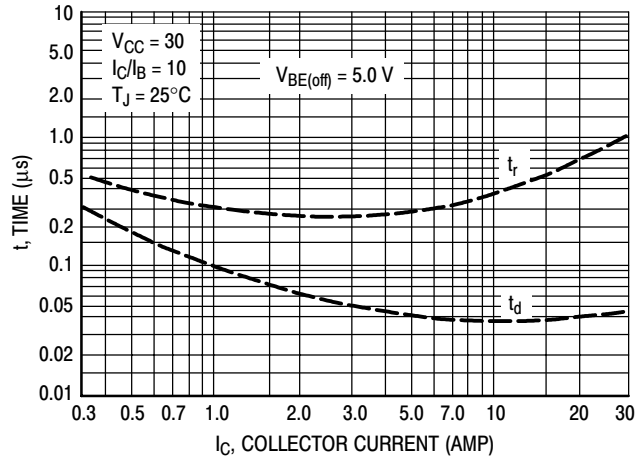


Figure 5. Turn-On Time

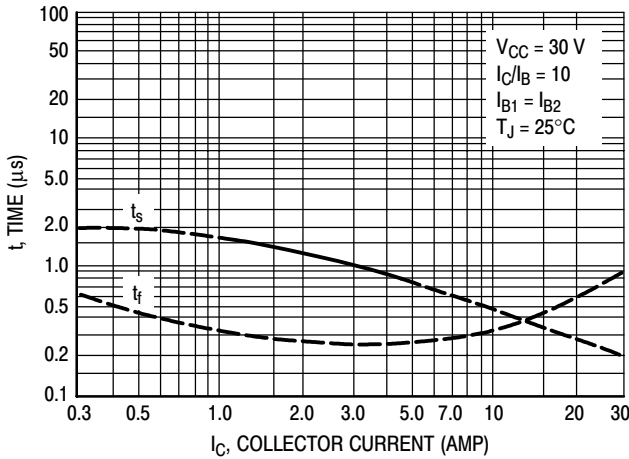


Figure 6. Turn-Off Time

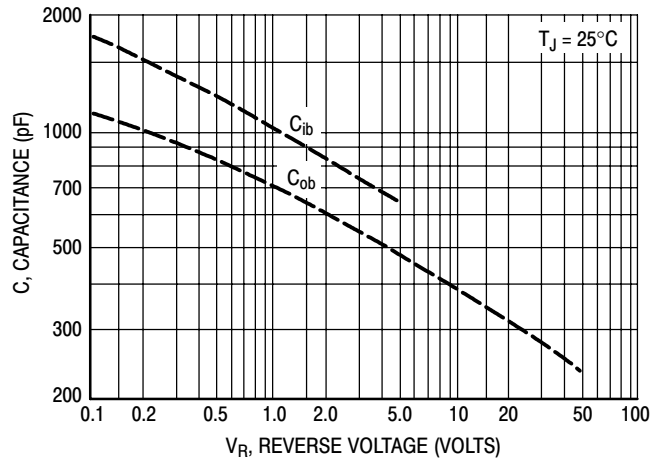


Figure 7. Capacitance

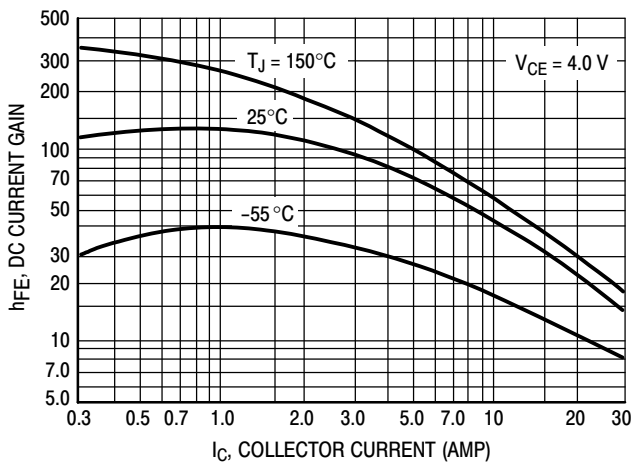


Figure 8. DC Current Gain

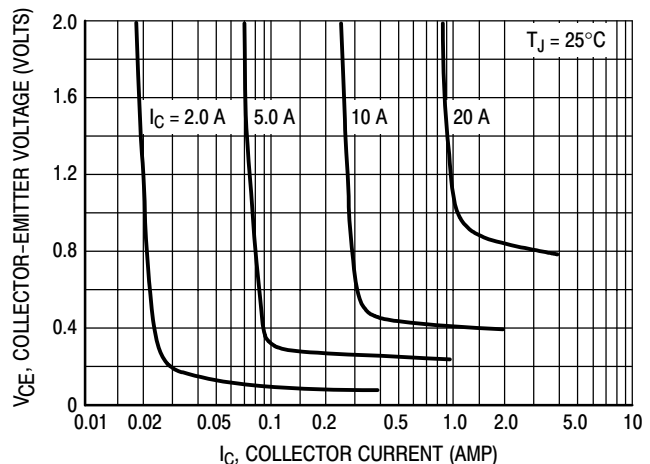
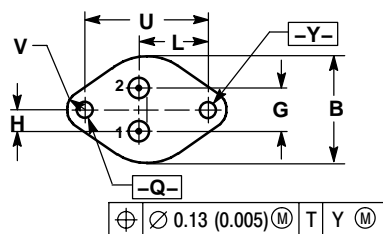
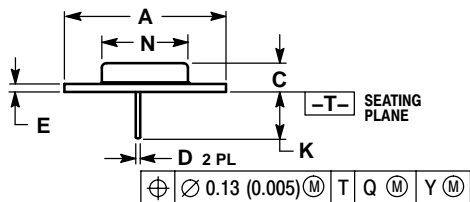


Figure 9. Collector Saturation Region

# 2N3771, 2N3772

## PACKAGE DIMENSIONS

### TO-204 (TO-3) CASE 1-07 ISSUE Z



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

**STYLE 1:**

1. BASE
  2. EMITTER
- CASE: COLLECTOR

**ON Semiconductor** and **ON** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### PUBLICATION ORDERING INFORMATION

**LITERATURE FULFILLMENT:**  
Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** orderlit@onsemi.com

**N. American Technical Support:** 800-282-9855 Toll Free USA/Canada  
**Europe, Middle East and Africa Technical Support:**  
Phone: 421 33 790 2910  
**Japan Customer Focus Center**  
Phone: 81-3-5773-3850

**ON Semiconductor Website:** [www.onsemi.com](http://www.onsemi.com)  
**Order Literature:** <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View 2N3772G on WIN SOURCE](#)

 [ON Semiconductor](#) Information

## Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management